

ZNBG3000 ZNBG3001

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	-0.6V to 15V
Supply Current	100mA
Drain Current (per FET) (set by R _{CAL1} and R _{CAL2})	0 to 15mA
Output Current	100mA
Operating Temperature	-30 to 70°C
Storage Temperature	-40 to 85°C

Power Dissipation (T_{amb}= 25°C)
 QSOP16 500mW

ELECTRICAL CHARACTERISTICS TEST CONDITIONS (Unless otherwise stated): T_{amb}= 25°C, V_{CC}=5V, I_D=10mA (R_{CAL1}=33kΩ)

SYMBOL	PARAMETER	CONDITIONS	LIMITS			UNITS
			Min	Typ	Max	
V _{CC}	Supply Voltage		5		12	V
I _{CC}	Supply Current	I _{D1} to I _{D3} =0 I _{D1} to I _{D3} =10mA			10 40	mA mA
V _{SUB}	Substrate Voltage (Internally generated)	I _{SUB} = 0 I _{SUB} = -200μA	-3.5	-2.8	-2 -2	V V
E _{ND} E _{NG}	Output Noise Drain Voltage Gate Voltage	C _G =4.7nF, C _D =10nF C _G =4.7nF, C _D =10nF			0.02 0.005	Vpkpk Vpkpk
f _O	Oscillator Freq.		200	330	800	kHz

DRAIN CHARACTERISTICS

I _{DO}	Output Current Range	Set by R _{CAL1}	0		15	mA
I _D	Current		8	10	12	mA
ΔI _{DV} ΔI _{DT}	Current Change with V _{CC} with T _j	V _{CC} =5 to 12V T _j =-30 to +70°C		0.5 0.05		%/V %/°C
V _D	Voltage	ZNBG3000 ZNBG3001 I _{D1} to I _{D3} =10mA	2 1.8	2.2 2	2.4 2.2	V V
ΔV _{DV} ΔV _{DT}	Voltage Change with V _{CC} with T _j	V _{CC} = 5 to 12V T _j = -30 to +70°C		0.5 50		%/V ppm

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SYMBOL	PARAMETER	CONDITIONS	LIMITS			UNITS
			Min	Typ	Max	

GATE CHARACTERISTICS

I_{G0}	Output Current Range		-30		2000	μA
V_{OL}	Output Voltage					
	Output Low	I_{D1} to $I_{D3}=12\text{mA}$ I_{G1} to $I_{G3}=0$	-3.5		-2	V
V_{OH}	Output High	I_{D1} to $I_{D3}=12\text{mA}$ I_{G1} to $I_{G3}= -10\mu\text{A}$	-3.5		-2	V
	Output High	I_{D1} to $I_{D3}= 8\text{mA}$ I_{G1} to $I_{G3}= 0$	0.4		1	V

Notes:

1. The negative bias voltages specified are generated on-chip using an internal oscillator. Two external capacitors, C_{NB} and C_{SUB} , of 47nF are required for this purpose.

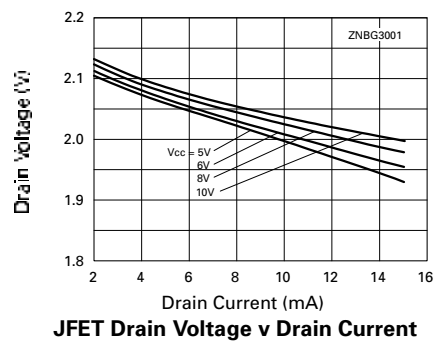
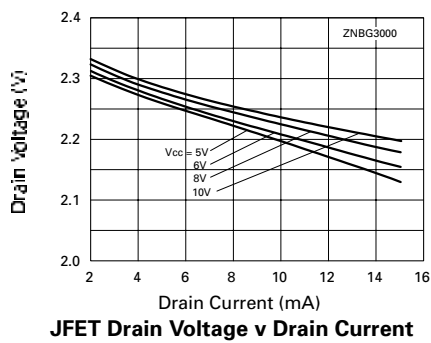
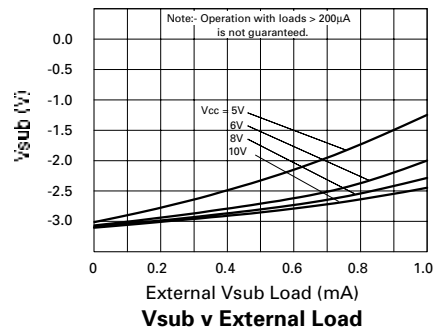
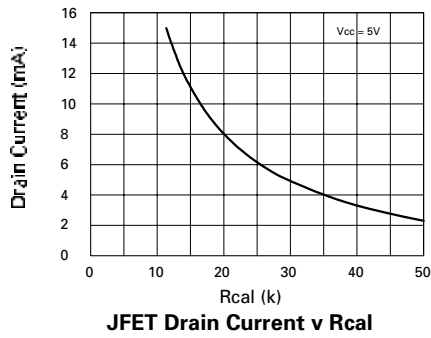
2. The characteristics are measured using an external reference resistors R_{CAL1} of value 33k Ω wired from pin R_{CAL1} to ground.

3. Noise voltage is not measured in production.

4. Noise voltage measurement is made with FETs and gate and drain capacitors in place on all outputs. C_G , 4.7nF, are connected between gate outputs and ground, C_D , 10nF, are connected between drain outputs and ground.

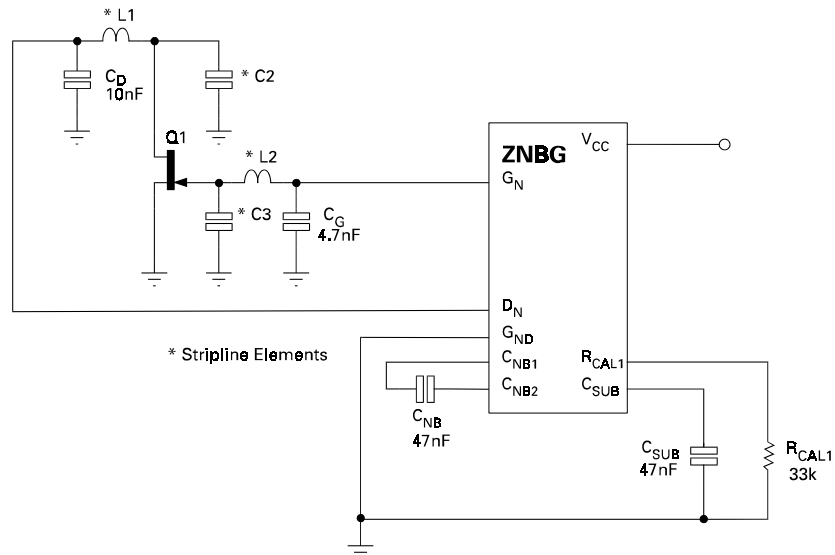
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TYPICAL CHARACTERISTICS



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TYPICAL APPLICATION CIRCUIT



APPLICATIONS INFORMATION

The above is a partial application circuit for the ZNBG series showing all external components required for appropriate biasing. The bias circuits are unconditionally stable over the full temperature range with the associated FETs and gate and drain capacitors in circuit.

Capacitors C_D and C_G ensure that residual power supply and substrate generator noise is not allowed to affect other external circuits which may be sensitive to RF interference. They also serve to suppress any potential RF feedthrough between stages via the ZNBG device. These capacitors are required for all stages used. Values of 10nF and 4.7nF respectively are recommended however this is design dependent and any value between 1nF and 100nF could be used.

The capacitors C_{NB} and C_{SUB} are an integral part of the ZNBGs negative supply generator. The negative bias voltage is generated on-chip using an internal oscillator. The required value of capacitors C_{NB} and C_{SUB} is 47nF. This generator produces a low current supply of approximately -3 volts. Although this generator is intended purely to bias the external FETs, it can be used to power other external circuits via the C_{SUB} pin.

Resistor R_{CAL1} sets the drain current at which all external FETs are operated. If any bias control circuit is not required, its related drain and gate connections may be left open circuit without affecting the operation of the remaining bias circuits. If all FETs associated with a current setting resistor are omitted, the particular R_{CAL} should still be included. The supply current can be reduced, if required, by using a high value R_{CAL} resistor (e.g. 470k).

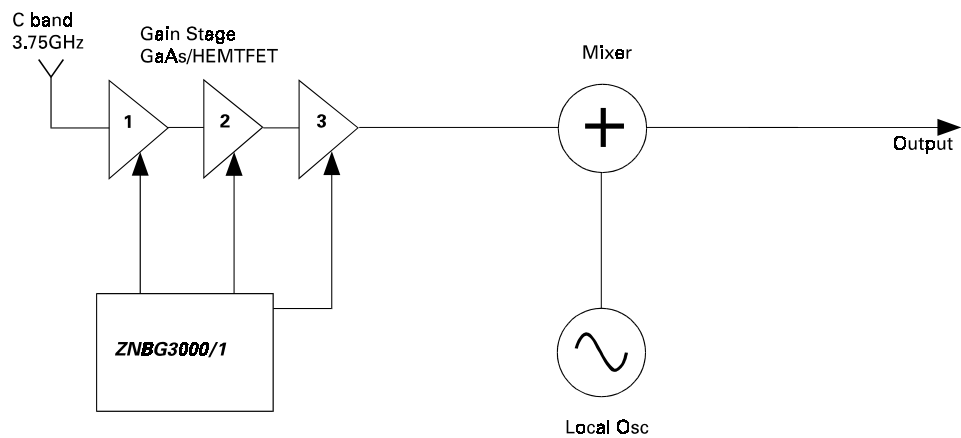
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APPLICATIONS INFORMATION (Continued)

The ZNBG devices have been designed to protect the external FETs from adverse operating conditions. With a JFET connected to any bias circuit, the gate output voltage of the bias circuit can not exceed the range -3.5V to 0.7V, under any conditions including powerup and powerdown transients. Should the negative bias generator be shorted or overloaded so that the drain current of the external FETs can no longer be controlled, the drain supply to FETs is shut down to avoid damage to the FETs by excessive drain current.

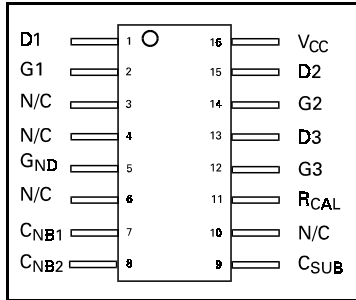
The following diagram show the ZNBG3000/1 in typical LNB applications.

Single in/Single out C band LNB block diagram



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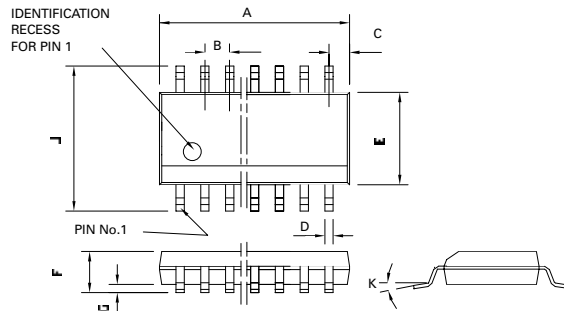
CONNECTION DIAGRAMS



ORDERING INFORMATION

Part Number	Package	Part Mark
ZNBG3000Q16	QSOP16	ZNBG3000
ZNBG3001Q16	QSOP16	ZNBG3001

PACKAGE DIMENSIONS



PIN	Millimetres		Inches	
	MIN	MAX	MIN	MAX
A	4.80	4.90	0.033	0.039
B	0.635		0.025 NOM	
C	0.177	0.267	0.007	0.011
D	0.20	0.30	0.008	0.012

E	3.81	3.99	0.15	0.157
F	1.35	1.75	0.053	0.069
G	0.10	0.25	0.004	0.01
J	5.79	6.20	0.228	0.244
K	0°	8°	0°	8°



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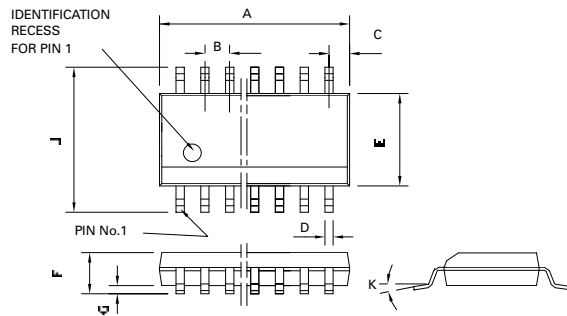
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ZNBG4000 ZNBG4001
ZNBG6000 ZNBG6001

ZNBG3000
ZNBG3001

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